NRVTSM260E

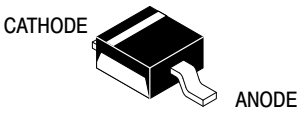
Surface Mount Trench Schottky Power Rectifier

POWERMITE®
Power Surface Mount Package

ON Semiconductor®

http://onsemi.com

SCHOTTKY TRENCH RECTIFIER
2.0 AMPERES, 60 VOLTS



POWERMITE
CASE 457

Features

- Low Profile − Maximum Height of 1.1 mm
- Small Footprint − Footprint Area of 8.45 mm^2
- Supplied in 12 mm Tape and Reel
- Low Thermal Resistance with Direct Thermal Path of Die on Exposed Cathode Heat Sink
- Fine Lithography Trench−based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- High Surge Capability
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q101 Qualified and PPAP Capable
- These are Pb−Free and Halide−Free Devices

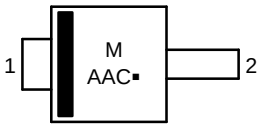
Typical Applications

- Switching Power Supplies including Adapters & Flat Panel Displays
- High Frequency and DC−DC Converters
- Freewheeling and OR−ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics:

- Powermite is JEDEC Registered as D0−216AA
- Case: Molded Epoxy
- Epoxy Meets UL 94 V−0 @ 0.125 in
- Weight: 16.3 mg (Approximately)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Maximum for 10 Seconds

MARKING DIAGRAM



M = Date Code
AAC = Device Code
▪ = Pb−Free Package
(Marking Style 1)

ORDERING INFORMATION

Device	Package	Shipping†
NRVTSM260ET1G	Powermite (Pb−Free)	3000 / Tape & Reel
NRVTSM260ET3G	Powermite (Pb−Free)	12000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	60	V
Average Rectified Forward Current (T_L = 162°C)	I_O	2.0	A
Peak Repetitive Forward Current (Square Wave, 20 kHz, T_L = 160°C)	I_{FRM}	4.0	A
Non−Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I_{FSM}	50	A
Storage and Operating Junction Temperature Range (Note 1)	T_{stg}, T_J	−55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The heat generated must be less than the thermal conductivity from Junction−to−Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction−to−Lead (Note 2)	Ψ_{JCL}	8.6	°C/W
Thermal Resistance, Junction−to−Ambient (Note 2)	$R_{\theta JA}$	80	°C/W
Thermal Resistance, Junction−to−Ambient (Note 3)	$R_{\theta JA}$	237	°C/W

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 4) (I_F = 1 A, T_J = 25°C) (I_F = 2 A, T_J = 25°C) (I_F = 1 A, T_J = 125°C) (I_F = 2 A, T_J = 125°C)	V_F	 0.55 0.65 0.47 0.58	V
Maximum Instantaneous Reverse Current (Note 4) (Rated dc Voltage, T_J = 25°C) (Rated dc Voltage, T_J = 125°C)	I_R	 12 3.0	 μA mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Mounted with 700 mm^2 copper pad size (Approximately 1 in^2) 1 oz FR4 Board.
3. Mounted with pad size approximately 20 mm^2 copper, 1 oz FR4 Board.
4. Pulse Test: Pulse Width ≤ 380 μs, Duty Cycle ≤ 2.0%.

TYPICAL CHARACTERISTICS

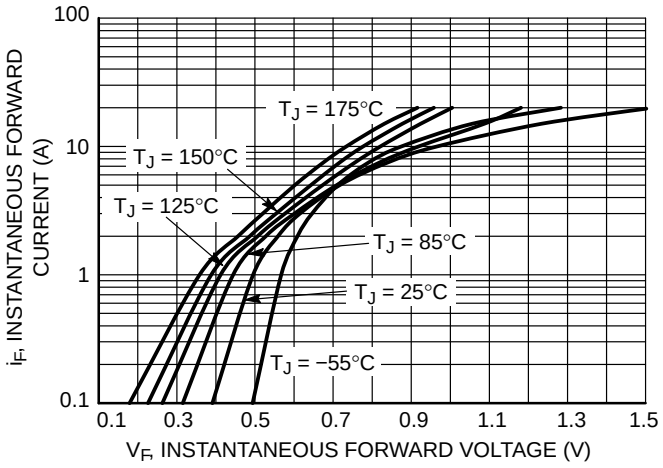

Figure 1. Typical Instantaneous Forward Characteristics

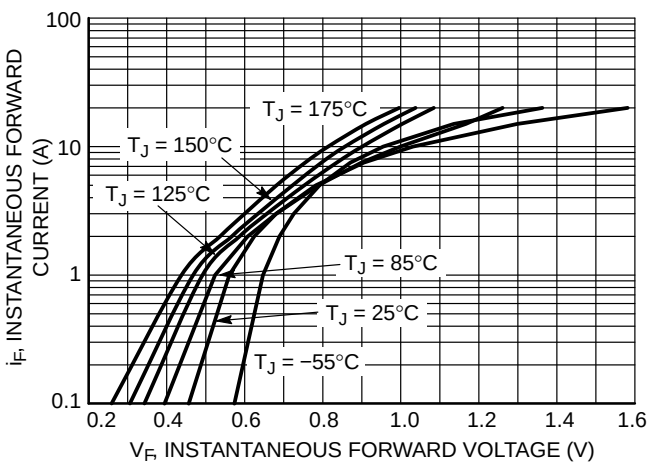

Figure 2. Maximum Instantaneous Forward Characteristics

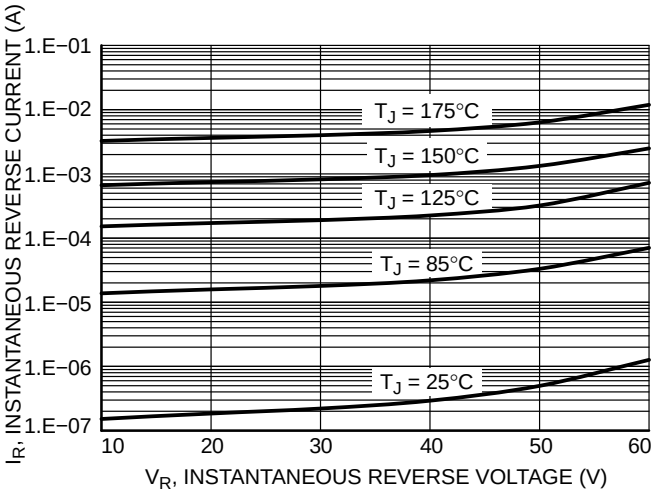

Figure 3. Typical Reverse Characteristics

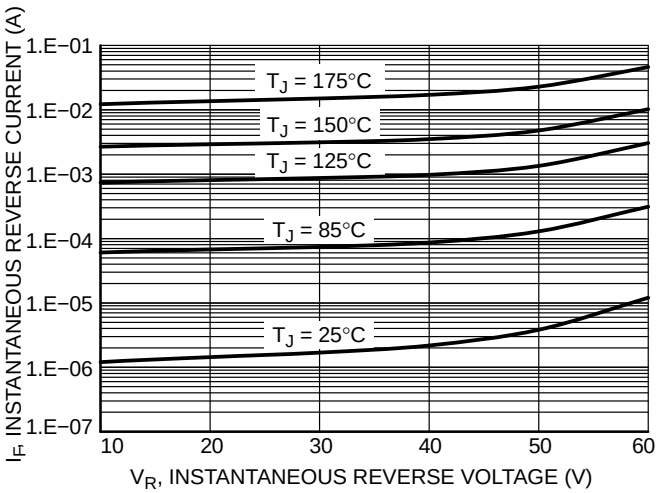

Figure 4. Maximum Reverse Characteristics

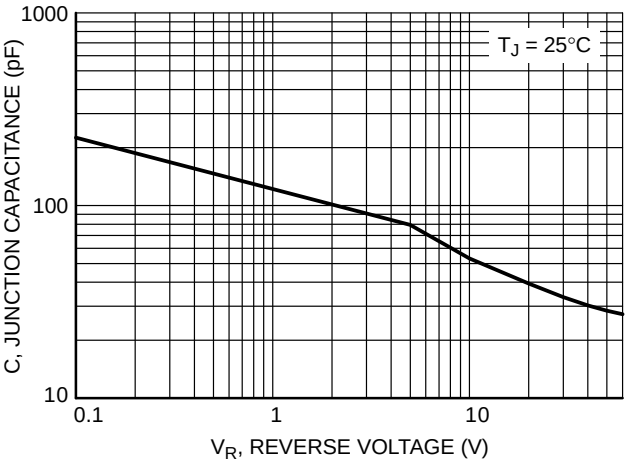

Figure 5. Typical Junction Capacitance

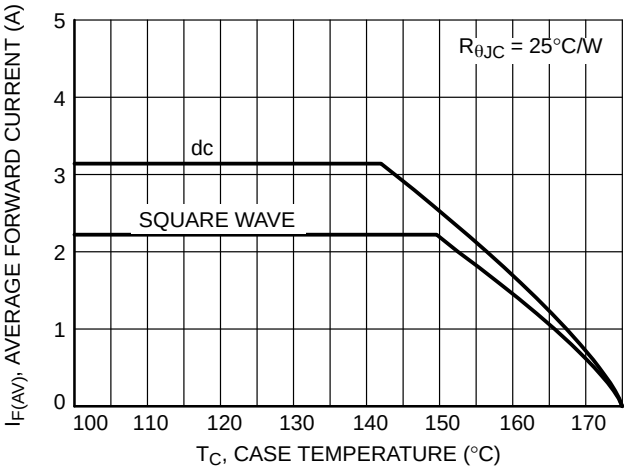

Figure 6. Current Derating

TYPICAL CHARACTERISTICS

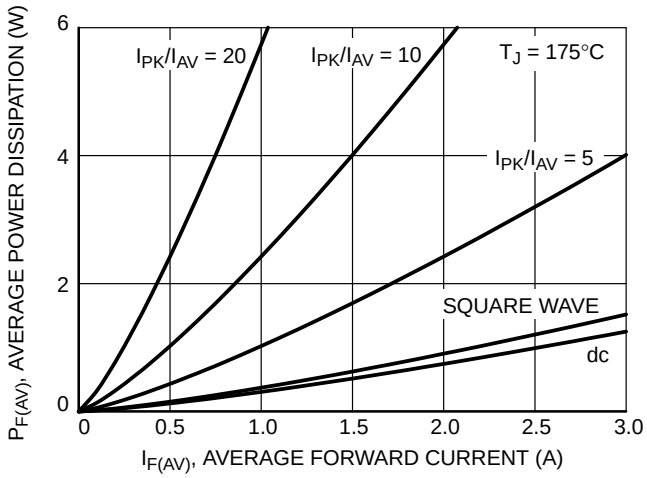

Figure 7. Forward Power Dissipation

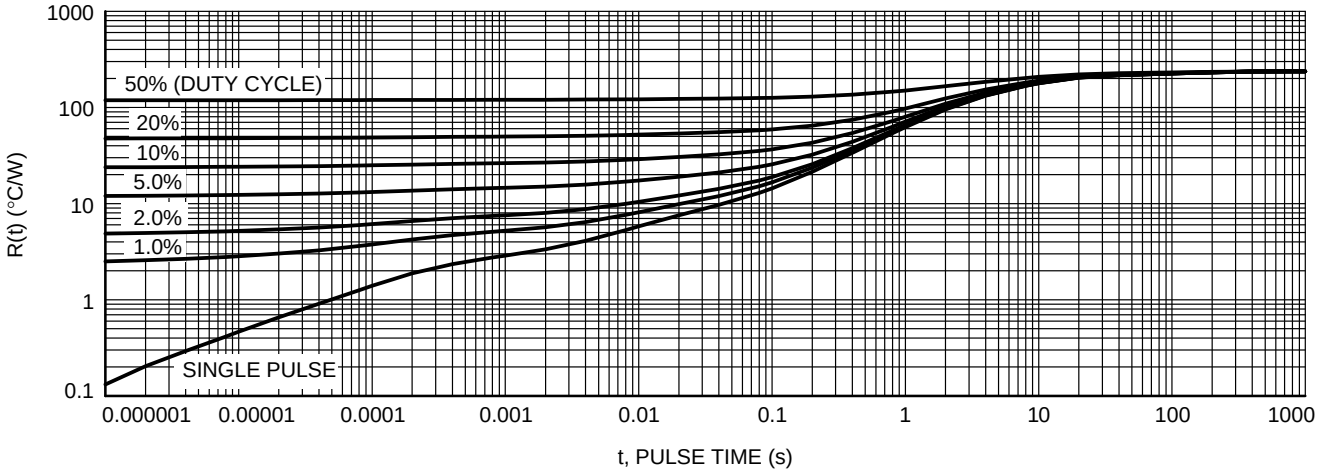

Figure 8. Thermal Response, Junction−to−Ambient (20 mm^2 pad)

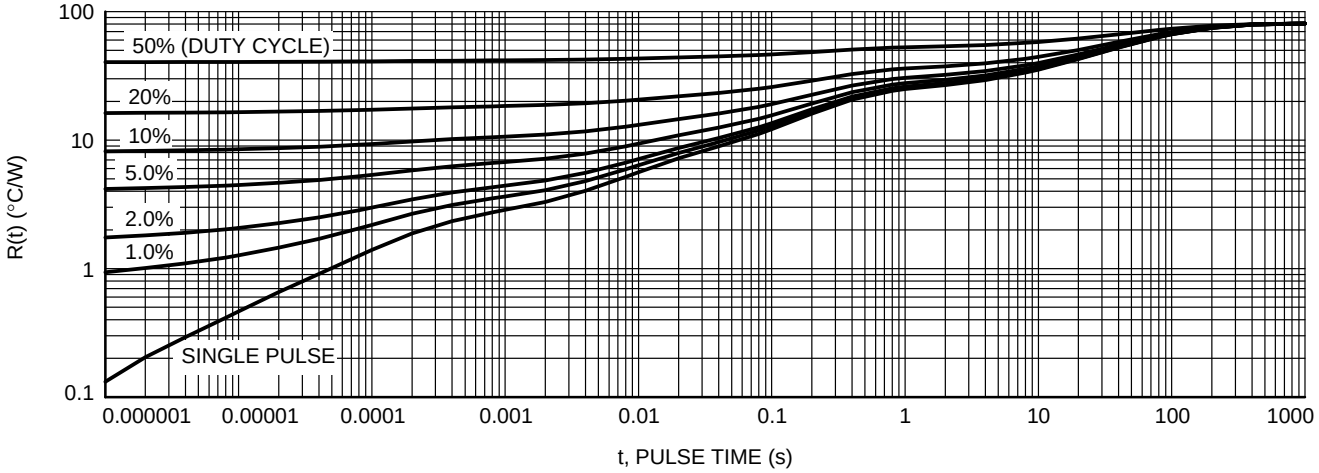

Figure 9. Thermal Response, Junction−to−Ambient (1 in^2 pad)

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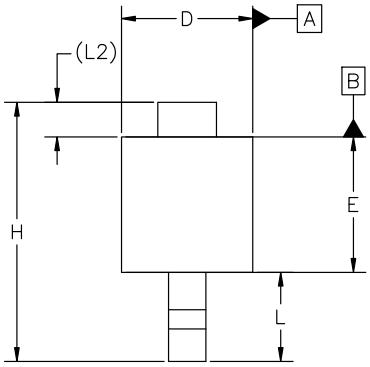
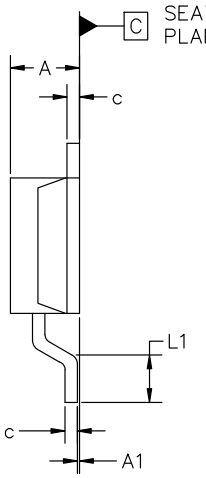
POWERMITE 1.90x1.96x1.00
CASE 457
ISSUE H

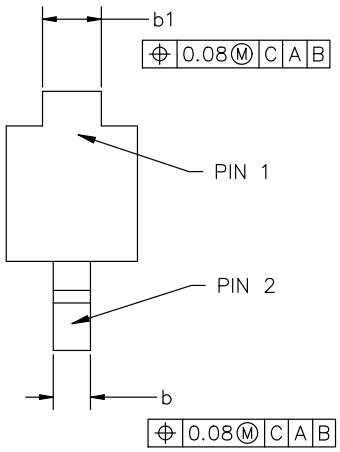
DATE 16 MAY 2025



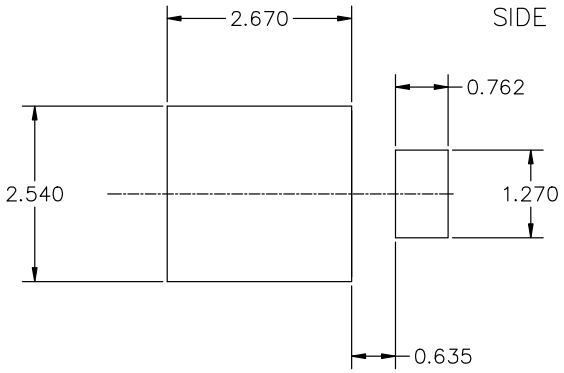
TOP VIEW



SIDE VIEW



BOTTOM VIEW



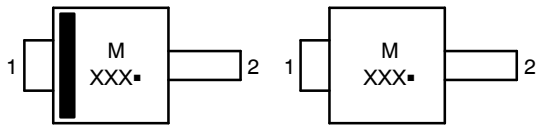
RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb−Free Strategy and Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

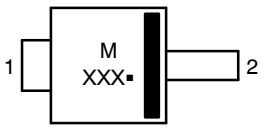
MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.85	1.00	1.15
A1	0.00	0.05	0.10
b	0.40	0.55	0.69
b1	0.70	0.85	1.00
c	0.10	0.18	0.25
D	1.75	1.90	2.05
E	1.75	1.96	2.18
H	3.60	3.75	3.90
L	1.20	1.35	1.50
L1	0.50	0.65	0.80
L2	0.50 REF		

NOTES:
1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION D & E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

GENERIC MARKING DIAGRAMS*



STYLE 1 **STYLE 2**



STYLE 3

XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

STYLE 1:
PIN 1. CATHODE
2. ANODE

STYLE 2:
PIN 1. ANODE OR CATHODE
2. CATHODE OR ANODE
(BI−DIRECTIONAL)

STYLE 3:
PIN 1. ANODE
2. CATHODE

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	**POWERMITE 1.90x1.96x1.00**		**PAGE 1 OF 1**

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